

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	50256	interlayer adj (insulat\$4 or dielectric) adj (layer or liner or film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 09:00
L2	116411	barrier adj (layer or liner or film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 06:58
L4	16519	etch adj stop\$4 adj (layer or liner or film)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:08
L5	523	1 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 06:49
L6	40	(etch adj stop\$4 adj (layer or liner or film)) with (oxide adj nitride adj oxide or ono)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 06:52
L7	2960	barrier adj (layer or liner or film) with gap	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 06:58
L8	7	barrier adj (layer or liner or film) with gap with 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 06:59
L9	1254	barrier adj (layer or liner or film) with 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:00

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L10	2318	(deposit\$4 or forming or formation) with (barrier adj (layer or liner or film)) with (chemical adj mechanical adj polish\$3 or cmp or planarization or planariz\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:09
L11	1838491	semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:02
L12	2156	10 and 11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:05
L14	467	4 and 10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:06
L15	772	etch adj stop\$4 adj (layer or liner or film) with gate adj (stack or electrode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:08
L18	13335	(chemical adj mechanical adj polish\$3 or cmp or planarization or planariz\$3) and (deposit\$4 or forming or formation) with (barrier adj (layer or liner or film))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:09
L19	55	15 and 18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 07:09
L20	0	(10/172354).APP.	USPAT; USOCR	OR	ON	2007/06/09 07:10
L21	67	("4409722" "4653025" "4740479" "4785341" "4805147" "4944682" "4966870" "5045916" "5072286" "5145799" "5173450" "5187638" "5227649" "5243203" "5246876" "5320975" "5334862").PN. OR ("5541427").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/09 08:04

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L22	2	"6686247".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 08:05
L23	20	("4964143" "5268330" "5547900" "5652176" "5763312" "5930672" "5953613" "5976939" "6025255" "6033962" "6124191" "6194784" "6251721" "6281062" "6316349" "6326270" "6335279" "6503818" "6528413" "6576948").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/09 08:11
L24	14	((("6335279") or ("6117723") or ("20030011017") or ("5652449") or ("20020132403") or ("20020052085") or ("20020185662") or ("6074915") or ("6251721") or ("6194784") or ("20020039835") or ("6194784") or ("6551901") or ("6146974") or ("6392310") or ("5652449")).PN.	US-PGPUB; USPAT	OR	OFF	2007/06/09 08:13
L25	7986	(interlayer adj (insulat\$4 or dielectric) adj (layer or liner or film)) with (nitride)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 09:00
L26	1966	438/197.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 09:00
L27	93	25 and 26	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/09 09:00